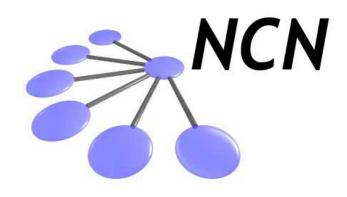


Network for Computational Nanotechnology (NCN)

Berkeley, Univ. of Illinois, Norfolk State, Northwestern, Purdue, UTEP

NEMO1D: Motivation / History / Key Insights



Gerhard Klimeck







Thanks to: NEMO Core Team Members

NEMO 1-D - 1994-1998

Roger Lake, Texas Instruments / UC Riverside
R. Chris Bowen, Texas Instruments / JPL / TI
Tim Boykin, U Alabama in Huntsville
Dan Blanks, Texas Instruments
William R. Frensley, UT Dallas

NEMO 1-D - 1998-2003

R. Chris Bowen, JPL
Tim Boykin, U Alabama in Huntsville

Post Docs / Students / Developers / Consultants:

Manhua Leng, Chenjing Fernando, Paul Sotirelis, Carlos Salazar-Lazaro, Bill McMahon, Daniela Francovicchio, Mukund Swaminathan, Dejan Jovanovic

Experimentalists:

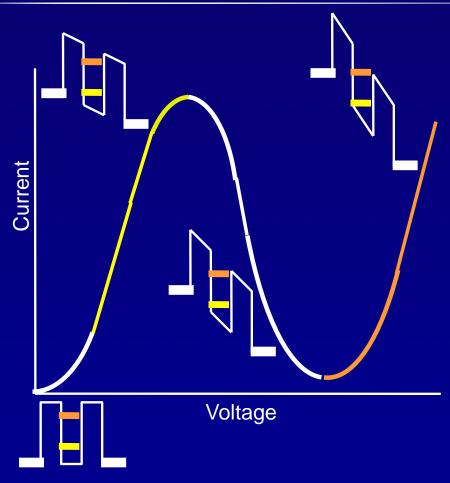
Alan Seabaugh, Ted Moise, Ed Beam, Tom Broekaert, Paul van der Wagt, Bobby Brar, Y. Chang (all TI), David Chow (HRL)

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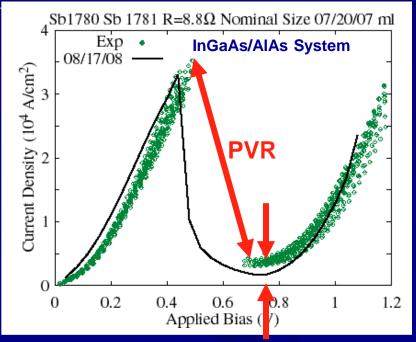




Basic Operation of a Resonant Tunneling Diode



Conduction band diagrams for different voltages and the resulting current flow NCN



12 different I-V curves: 2 wafers, 3 mesa sizes, 2 bias directions

PVR – Peak-to-Valley-Ratio

1994: Best experiment PVR=80

=> On-Off-Ratio should to be >1,000

1994: What is the valley current physics?

1997: Can overlay experiment and theory. What are the key insights?



Resonant Tunneling Diodes in 1994

Potential:

- THz operation limited only by tunneling time
- NDR => fast oscillations
- NDR => stable latches, digital logic

Challenges:

- Valley current too high => high "off" state current
- No production-like experiments => repeatability issues
- No generally accepted device modeling theory

⇒Nanoelectronic Modeling – NEMO

- ⇒Software tool that:
- Quantitative modeling
- Predictive design
- Physics-based understanding







State-of-the-art RTD Modeling and Simulation **Knowledge 1994**

Knowledge / Availability:

- 1-D Poisson Schrödinger
 - » Quantum transmitting boundary conditions (QTBM), flatband (Lent)
 - » Single band, effective mass, no scattering ("everyone")
 - » Multiple Sequential Scattering (Roblin)
 - » Tight binding, no scattering (Boykin, Ting)
- Density Function
 - » Single band, no scattering, time dependent (Ferry)
- Wigner Function
 - » Single band with empirical scattering (Frensley)
- NEGF
 - » Single band with scattering (Lake, Jauho)
 - » Single band with charge self-consistency (Klimeck)
- SCATTERING is the source of the valley current

Limitations:

- Tiny device simulation domains no extended contact regions
- No realistic scattering models
- Computation too expensive for engineering (we can build this in one month)
- No predictive theory, modeling, and simulation

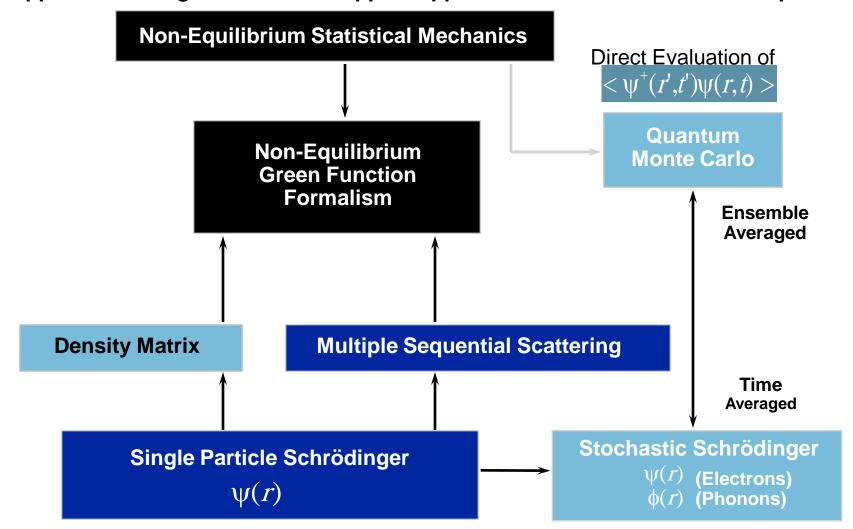






Available and Explored Theories

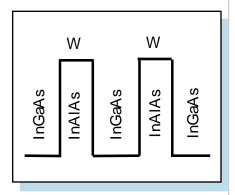
- The non-equilibrium Green function formalism underlies NEMO.
- All of the approaches shown were considered.
- Approaches in light blue were dropped. Approaches in dark blue were incorporated.



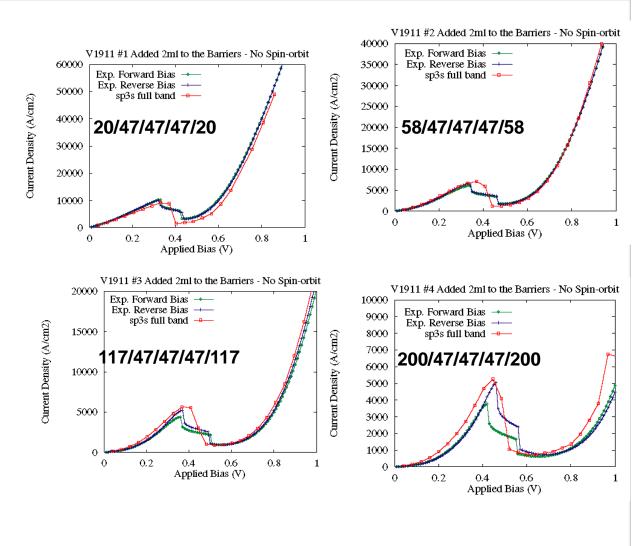


4 Stack RTD with Spacer Variation

Vary Spacer Length



Four nominally symmetric devices: 20/47/47/47/20 A [1] 58/47/47/47/48 A [2] 117/47/47/47/117 [3] 200/47/47/47/200 [4]



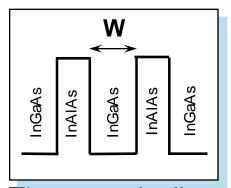






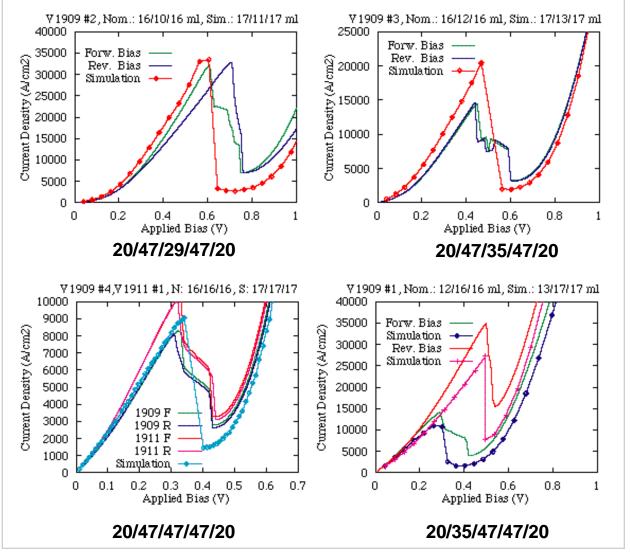
4 Stack RTD with Well Width Variation

Vary Well Width



Three nominally symmetric devices: 47/29/47 A [1] 47/35/47 A [2] 47/47/47 A [3] One asymmetric device: 35/47/47 A

Gerhard Klimeck

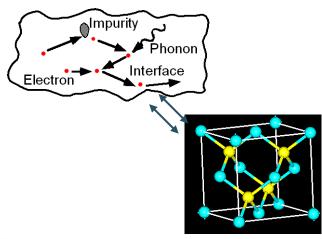


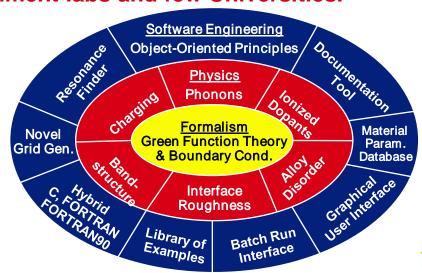




NEMO: A User-friendly Quantum Device Design Tool

- NEMO 1-D was developed under a NSA/NRO contract to Texas Instruments and Raytheon from '93-'98 (>50,000 person hours, 250,000 lines of code).
- NEMO 1-D maintained and NEMO 3-D developed at JPL '98-'03 (>14000 person hours) under NASA, NSA, and ONR funding.
- NEMO is THE state-of-the-art quantum device design tool.
 - » First target: transport through resonant tunneling diodes (high speed electronics).
 - » Second target: electronic structure in realistically large nano devices (detectors).
 - » Third target: qbit device simulation.
 - » Ultimate target: Educational tool heterostructures, bandstructure, transport.
- Bridges the gap between device engineering and quantum physics.
- Based on Non-Equilibrium Green function formalism NEGF Datta, Lake, Klimeck.
- Currently used by limited number of government labs and few Universities.







State-of-the-art RTD Modeling and Simulation Knowledge 1998

Knowledge:

- Scattering inside RTD
 - » Only important at low temperatures
 - » Not important for room temperature, high performance
- Scattering inside extended contacts
 - » Of critical importance at any temperature
- Charge self-consistency
 - » Critical everywhere, contacts and central device
- Bandstructure atomistic device resolution
 - » Critical for understanding high temperature, high performance devices
- NEGF is the baseline of an industrial strength simulator

Availability:

- An engineering modeling and design tool for 1D heterostructures
- Experimentally verified analysis and design







Releasing NEMO1-D has been a Struggle

Even a movie was made!



Currently only available through JPL for government use!

We need public-domain codes as field develops!







NEMO 3-D can be found for free at: https://nanohub.org/groups/nemo_3d_distribution

The other Nemo has also been found:

